## NSN 5961-01-066-7183

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-066-7183 **Inclosure Material:** Glass **Overall Length:** 0.110 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.110 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 72.0 peak-point voltage **Current Rating Per Characteristic:** 10.00 milliamperes forward current, average peak and 5.00 milliamperes source cutoff current preset **Capacitance Rating In Picofarads:** 5.0 **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/269 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No